NPN Triple Diffused Planar Silicon Transistor



2SC3990

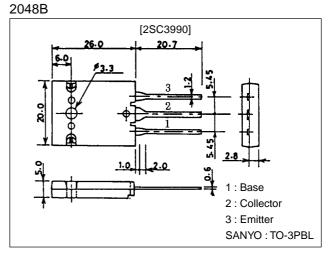
# 500V/35A Switching Regulator Applications

### Features

- $\cdot$  High breakdown voltage, high reliability.
- · Fast switching speed.
- $\cdot$  Wide ASO.
- · Adoption of MBIT process.

## **Package Dimensions**

unit:mm



# **Specifications**

#### Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit	
Collector-to-Base Voltage	V <sub>CBO</sub>		800	V	
Collector-to-Emitter Voltage	VCEO		500	V	
Emitter-to-Base Voltage	VEBO		7	V	
Collector Current	IC		35	А	
Collector Current (Pulse)	ICP	PW≤300µs, duty cycle≤10%	50	A	
Base Current	۱ <sub>B</sub>		12	A	
Collector Dissipation	PC	Tc=25°C	250	W	
Junction Temperature	Tj		150	°C	
Storage Temperature	Tstg		-55 to +150	°C	

### **Electrical Characteristics at Ta = 25°C**

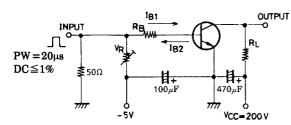
Parameter	Symbol	Conditions	Unit
		min typ max	
Collector Cutoff Current	I <sub>CBO</sub>	V <sub>CB</sub> =500V, I <sub>E</sub> =0 10	μΑ
Emitter Cutoff Current	IEBO	V <sub>EB</sub> =5V, I <sub>C</sub> =0 10	μΑ
DC Current Gain	h <sub>FE</sub> 1	V <sub>CE</sub> =5V, I <sub>C</sub> =3.2A 15* 50*	
	h <sub>FE</sub> 2	V <sub>CE</sub> =5V, I <sub>C</sub> =16A 8	
Gain-Bandwidth Product	fT	V <sub>CE</sub> =10V, I <sub>C</sub> =3.2A 18	MHz
Output Capacitance	Cob	V <sub>CB</sub> =10V, f=1MHz 400	pF
* : The 2SC3990 is classified by 3.2A h <sub>FE</sub> as foll	ows: 15	L 30 20 M 40 30 N 50	

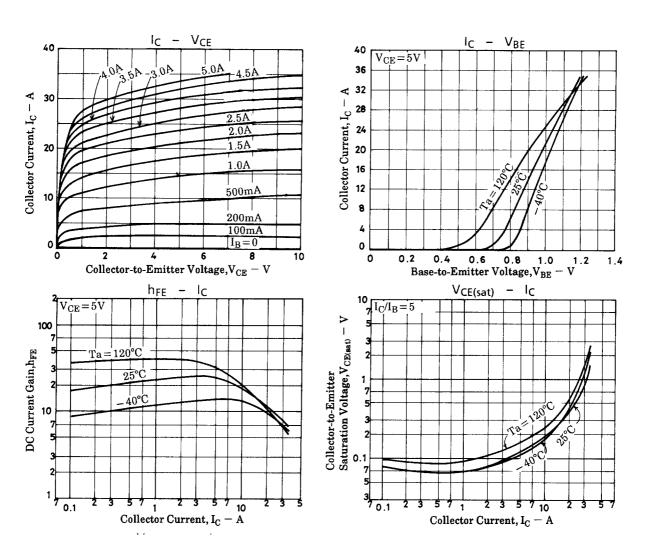
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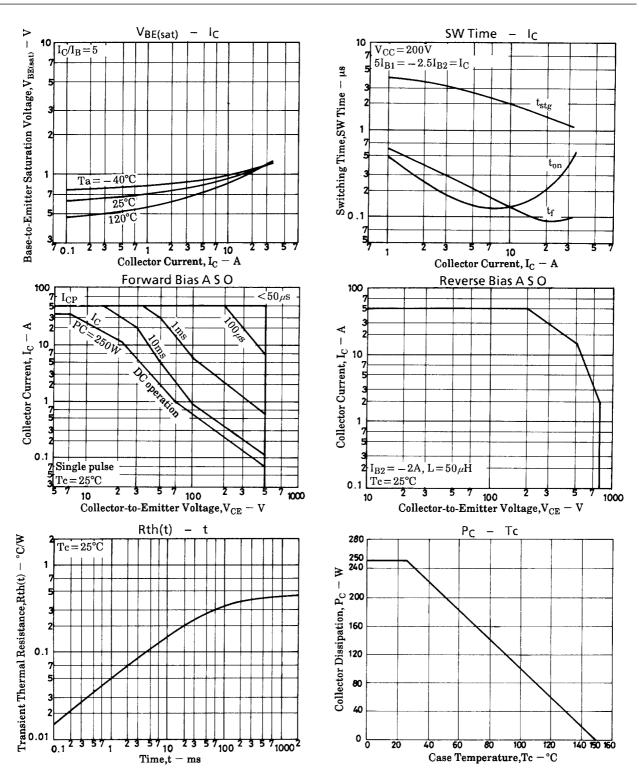
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Parameter	Symbol	Conditions	Ratings			Unit
	Symbol		min	typ	max	
Collector-to-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =16A, I <sub>B</sub> =3.2A			1.0	V
Base-to-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =16A, I <sub>B</sub> =3.2A			1.5	V
Collector-to-Base Breakdown Voltage	V <sub>(BR)</sub> CBO	I <sub>C</sub> =1mA, I <sub>E</sub> =0	800			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I <sub>C</sub> =10mA, R <sub>BE</sub> =∞	500			V
Emitter-to-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =1mA, I <sub>C</sub> =0	7			V
Collector-to-Emitter Sustain Voltage	VCEX(sus)	I <sub>C</sub> =15A, I <sub>B1</sub> =-I <sub>B2</sub> =-2A, L=200µH, clamped	500			V
Turn-ON Time	ton	$V_{CC}$ =200V, 5I <sub>B1</sub> =-2.5I <sub>B2</sub> =I <sub>C</sub> =18A, R <sub>L</sub> =11.1 $\Omega$			0.5	μs
Storage Time	t <sub>stg</sub>	$V_{CC}$ =200V, 5I <sub>B1</sub> =-2.5I <sub>B2</sub> =I <sub>C</sub> =18A, R <sub>L</sub> =11.1 $\Omega$			3.0	μs
Fall Time	t <sub>f</sub>	$V_{CC}$ =200V, 5I <sub>B1</sub> =-2.5I <sub>B2</sub> =I <sub>C</sub> =18A, R <sub>L</sub> =11.1 $\Omega$			0.3	μs

### **Switching Time Test Circuit**







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